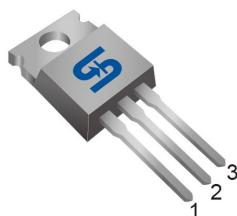


TO-220



ITO-220



Pin Definition:

1. Gate
2. Drain
3. Source

TO-252  
(DPAK)



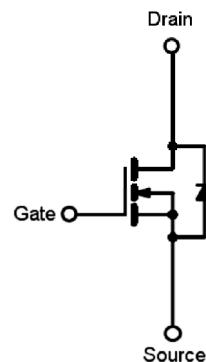
### Key Parameter Performance

Parameter	Value	Unit
$V_{DS}$	60	V
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	23
	$V_{GS} = 4.5V$	28
$Q_g$	28	nC

### Features

100% avalanche tested  
Fast Switching

### Block Diagram



N-Channel MOSFET

### Absolute Maximum Ratings ( $T_c = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit			Unit
		TO-220	ITO-220	DPAK	
Drain-Source Voltage	$V_{DS}$	60			V
Gate-Source Voltage	$V_{GS}$		$\pm 20$		V
Continuous Drain Current ( <sup>Note 1</sup> )	$I_D$	$T_c = 25^\circ C$	50*		A
		$T_c = 100^\circ C$	32*		A
Pulsed Drain Current ( <sup>Note 2</sup> )	$I_{DM}$	200			A
Single Pulse Avalanche Energy ( <sup>Note 3</sup> )	$E_{AS}$	42			mJ
Power Dissipation @ $T_c = 25^\circ C$	$P_D$	104	42	53	W
Operating Junction Temperature	$T_J$	150			$^\circ C$
Storage Temperature Range	$T_{STG}$	-55 to +150			$^\circ C$

### Thermal Performance

Parameter	Symbol	Limit			Unit
		TO-220	ITO-220	DPAK	
Thermal Resistance - Junction to Case	R <sub>JC</sub>	1.2	3	2	°C/W
Thermal Resistance - Junction to Ambient	R <sub>JA</sub>	62	62	62	

### Electrical Specifications (T<sub>C</sub> = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	BV <sub>DSS</sub>	60	--	--	V
Drain-Source On-State Resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A	R <sub>DS(ON)</sub>	--	20	23	m
	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 12A		--	23	28	
Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	V <sub>GS(TH)</sub>	1.2	1.8	2.5	V
Zero Gate Voltage Drain Current	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V	I <sub>DSS</sub>	--	--	1	μA
	V <sub>DS</sub> = 48V, T <sub>J</sub> = 125°C		--	--	10	
Gate Body Leakage	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V	I <sub>GSS</sub>	--	--	±100	nA
Forward Transconductance <sup>(Note 4)</sup>	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10A	g <sub>fs</sub>	--	9	--	S
<b>Dynamic</b>						
Total Gate Charge <sup>(Note 4,5)</sup>	V <sub>DS</sub> = 30V, I <sub>D</sub> = 15A, V <sub>GS</sub> = 10V	Q <sub>g</sub>	--	28	--	nC
Gate-Source Charge <sup>(Note 4,5)</sup>		Q <sub>gs</sub>	--	3.5	--	
Gate-Drain Charge <sup>(Note 4,5)</sup>		Q <sub>gd</sub>	--	6.5	--	
Input Capacitance	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz	C <sub>iss</sub>	--	1680	--	pF
Output Capacitance		C <sub>oss</sub>	--	115	--	
Reverse Transfer Capacitance		C <sub>rss</sub>	--	85	--	
<b>Switching</b>						
Turn-On Delay Time <sup>(Note 4,5)</sup>	V <sub>DD</sub> = 30V, I <sub>D</sub> = 1A, V <sub>GS</sub> = 10V, R <sub>G</sub> = 6	t <sub>d(on)</sub>	--	7.2	--	ns
Turn-On Rise Time <sup>(Note 4,5)</sup>		t <sub>r</sub>	--	38	--	
Turn-Off Delay Time <sup>(Note 4,5)</sup>		t <sub>d(off)</sub>	--	34	--	
Turn-Off Fall Time <sup>(Note 4,5)</sup>		t <sub>f</sub>	--	8.2	--	

### Source-Drain Diode Ratings and Characteristic

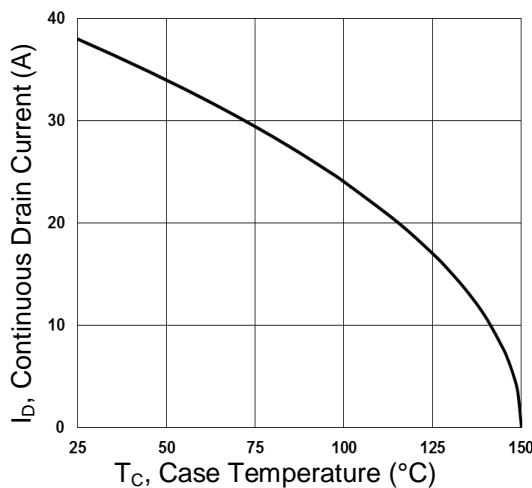
Maximum Continuous Drain-Source Diode Forward Current	Integral reverse diode in the MOSFET	I <sub>S</sub>	--	--	50	A
Maximum Pulse Drain-Source Diode Forward Current		I <sub>SM</sub>	--	--	200	A
Diode-Source Forward Voltage	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1A	V <sub>SD</sub>	--	--	1	V
Reverse Recovery Time <sup>(Note 4)</sup>	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1A dI <sub>F</sub> /dt = 100A/μs	t <sub>rr</sub>	--	19.6	--	ns
		Q <sub>rr</sub>	--	14.2	--	

### Note:

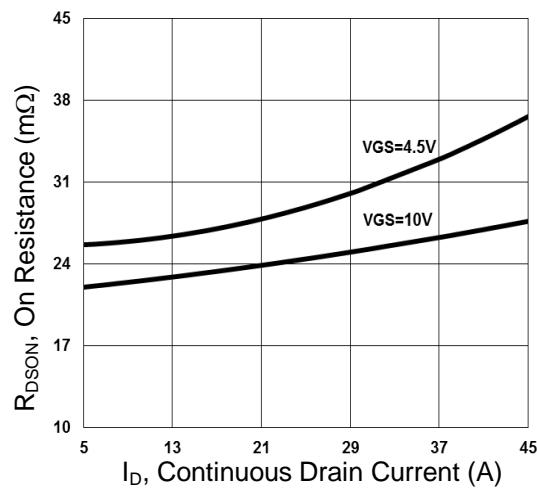
- Limited by maximum junction temperature
- Pulse width limited by safe operating area
- L = 0.1mH, I<sub>AS</sub> = 29A, V<sub>DD</sub> = 25V, R<sub>G</sub> = 25 , Starting T<sub>J</sub> = 25°C
- Pulse test: pulse width m300μs, duty cycle m2%
- Switching time is essentially independent of operating temperature.

### Electrical Characteristics Curve

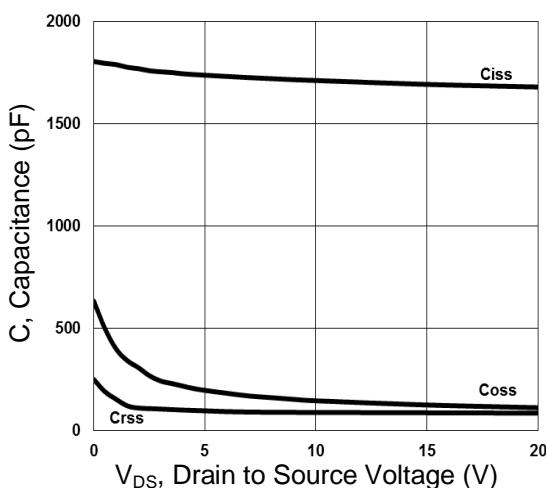
Continuous Drain Current vs.  $T_C$



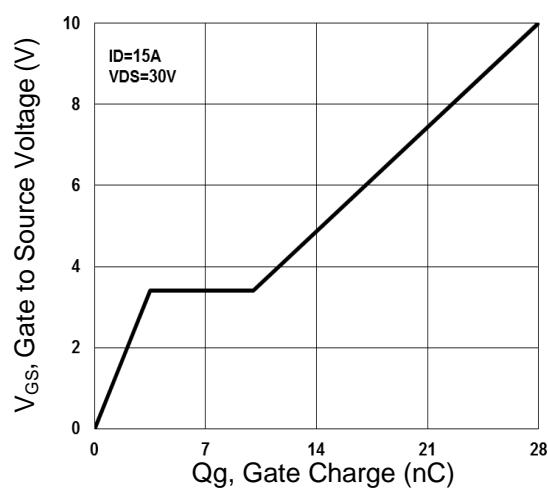
RDS<sub>ON</sub> vs. Continuous Drain Current



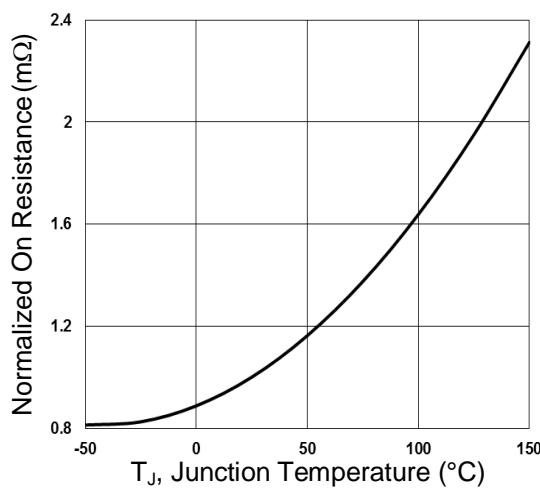
Capacitance



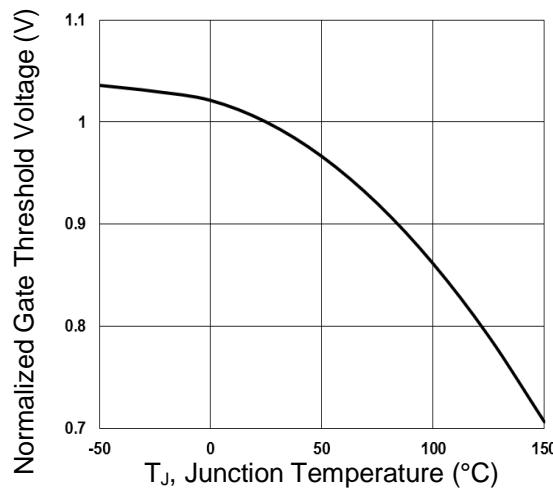
Gate Charge



On-Resistance vs. Junction Temperature

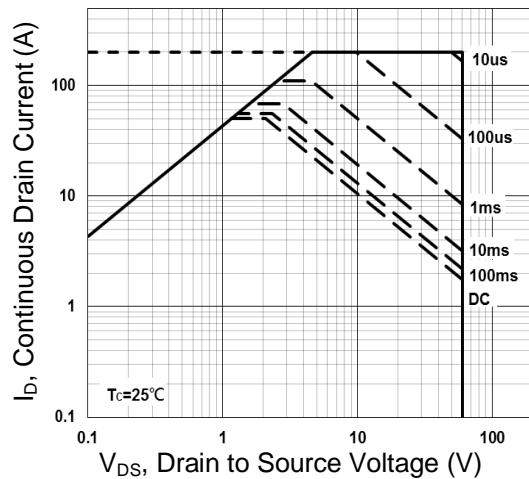


Threshold Voltage vs. Junction Temperature

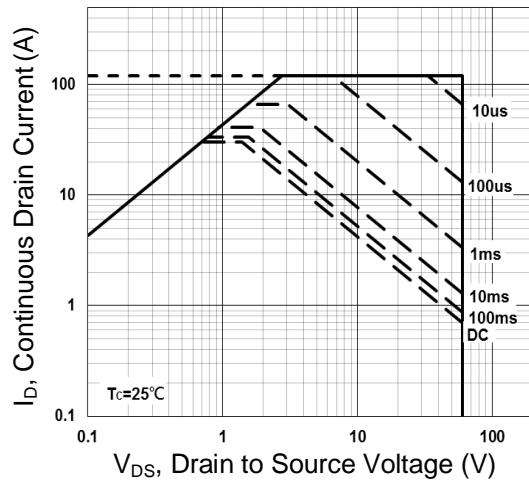


### Electrical Characteristics Curve

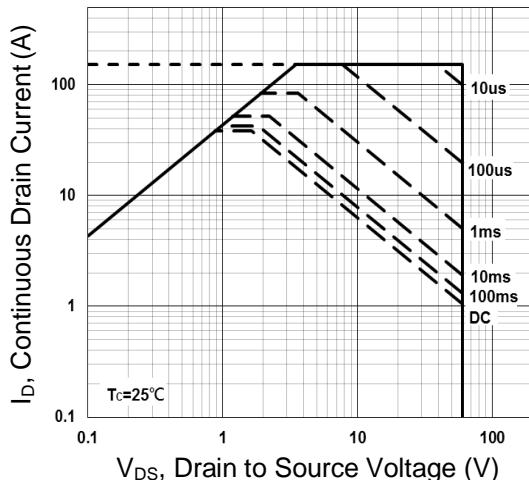
Maximum Safe Operating Area (TO-220)



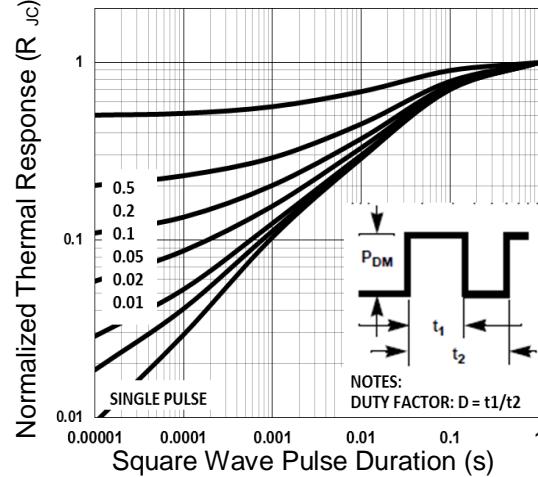
Maximum Safe Operating Area (ITO-220)



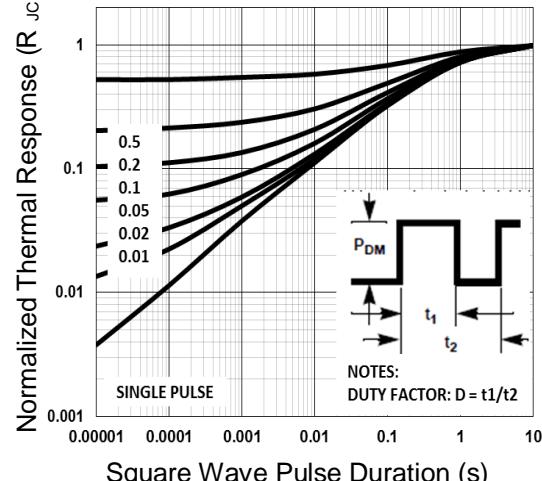
Maximum Safe Operating Area (TO-252)



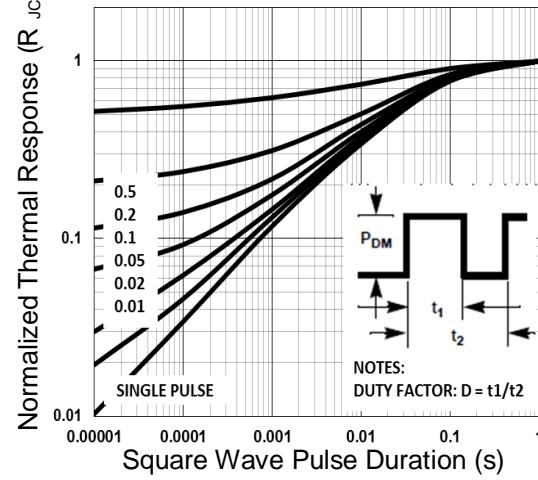
Normalized Thermal Transient Impedance (TO-220)



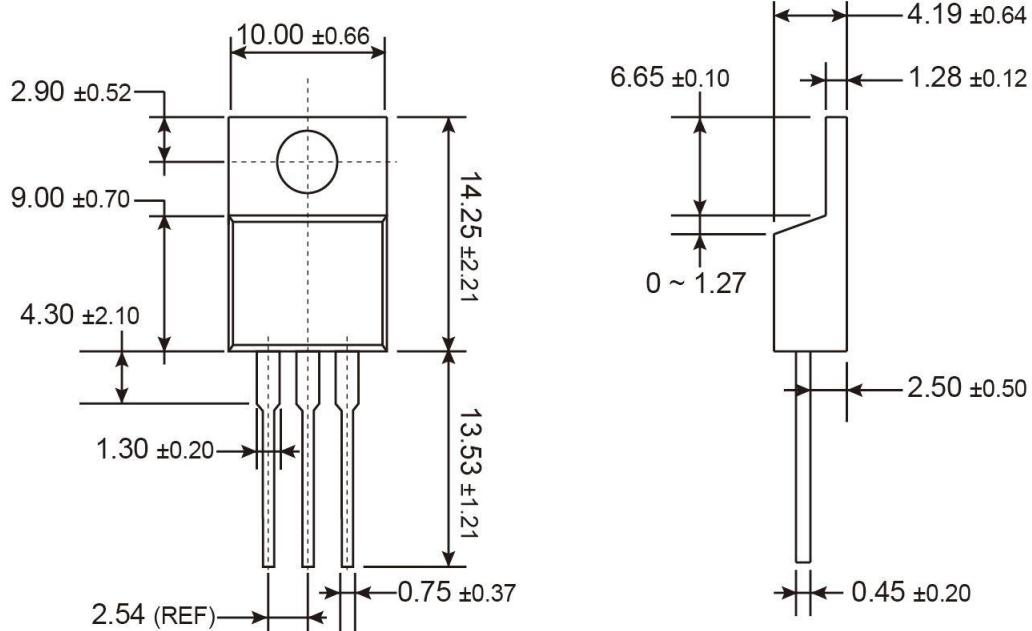
Normalized Thermal Transient Impedance (ITO-220)



Normalized Thermal Transient Impedance (TO-252)

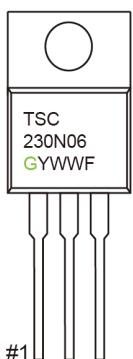


## **TO-220 Mechanical Drawing**



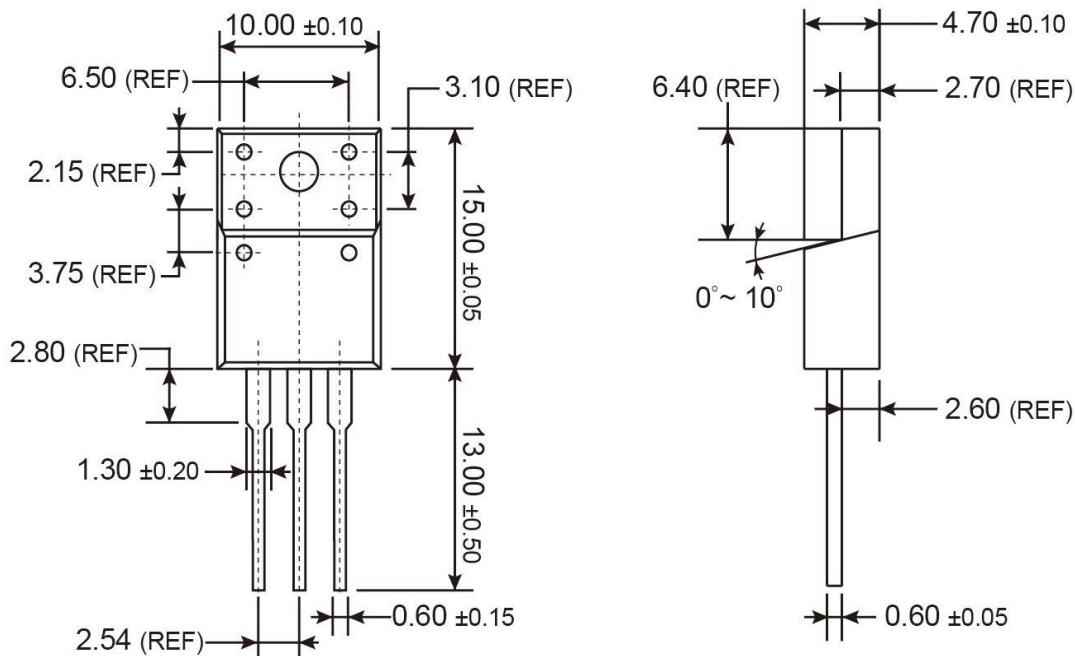
Unit: Millimeters

# Marking Diagram



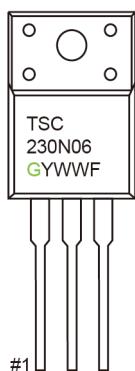
**G** = Halogen Free  
**Y** = Year Code  
**WW** = Week Code (01~52)  
**F** = Factory Code

## ITO-220 Mechanical Drawing



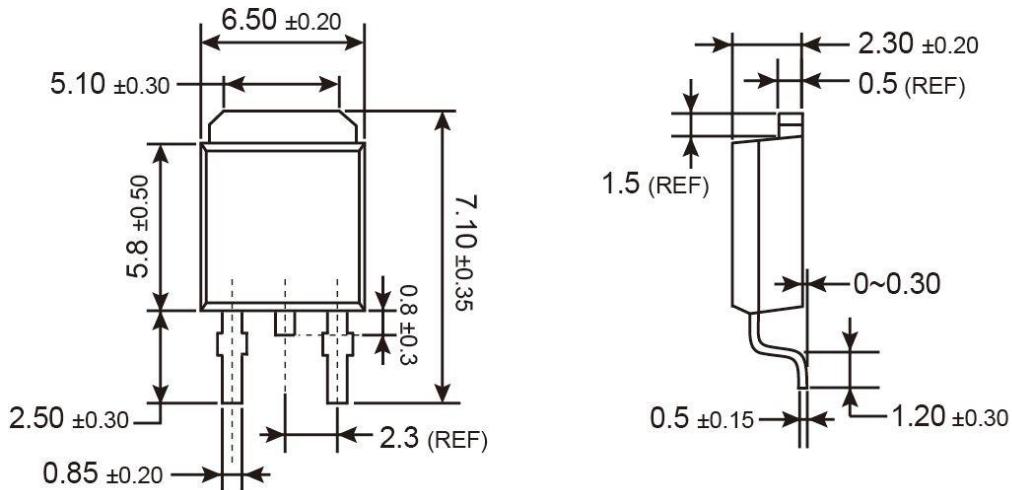
Unit: Millimeters

## Marking Diagram



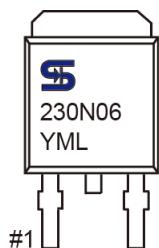
- G** = Halogen Free
- Y** = Year Code
- WW** = Week Code (01~52)
- F** = Factory Code

## TO-252 Mechanical Drawing



Unit: Millimeters

## Marking Diagram



- Y** = Year Code
- M** = Month Code for Halogen Free Product  
(O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep,  
X=Oct, Y=Nov, Z=Dec)
- L** = Lot Code

## Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.